

Reconfigurable Cavity Bandpass Filters Using Fluid Dielectric

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Abstract—A novel method for the development of a reconfigurable cavity bandpass filter using fluid dielectric is proposed. Dielectric material can produce an effective permittivity $\varepsilon_{\mathrm{eff}}$ of the resonant mode when it is loaded into the cavity. Thus, a tube filled with fluid dielectric, e.g., distilled water, can achieve controlled and reversible ε_{eff} by adjusting the amount of water in the tube. The same manner of resonant frequency can be achieved as the resonant frequency is related to $\varepsilon_{\mathrm{eff}}$, and then frequency tuning is realized. The fluid property can realize easier and faster tuning mechanism than conventional solid dielectric. As $\varepsilon_{\rm eff}$ is affected by the loaded dielectric parallel to the electric field, a triple-mode resonator with resonant modes TE_{101} , TE_{011} , and TM₁₁₀, which have orthogonal electric fields, is investigated to realize tri-band reconfiguration. The $\varepsilon_{\rm eff}$, as well as the resonant frequencies, corresponding to each mode can be individually controlled by adjusting their related water posts. Then, reconfigurable single-band and tri-band bandpass filters are designed. A reconfigurable tri-band cavity filter using a triple-mode cavity resonator and fluid dielectric with individual and continuous frequency tuning is reported for the first time. Finally, the reconfigurable tri-band filter is fabricated and measured to validate the concept.

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Index Terms—Bandpass filters, distilled water, fluid dielectric, metal cavity, reconfigurable cavity filter, triplemode resonator (TMR).

I. INTRODUCTION

R ECONFIGURABLE devices are highly demanded for modern communication systems with varying frequencies and multiband operations. Reconfigurable filters are among the key components for emerging wideband and multifunctional RF front-ends. The most reported reconfigurable filters are implemented on the planar circuits using the varactor-tuned resonators [1]–[7], as the varactors are easily integrated on the planar circuits. Recently, novel reconfigurable planar filters based on microfluidical tuning are reported in [8]–[12]. In [8]–[10], the fluid water is used to modify the relative permittivity of substrate below the planar transmission line, leading to a shift of the resonant frequency. In [11] and [12], liquid metal is utilized to design tunable planar filters by introducing controlled capacitive loading.

Compared to planar filters, metal cavity filters have a relatively large size, but high unloaded Q-factor and high breakdown voltage, thus, cavity filter are highly demanded in communication systems requiring high power capacity, high selectivity, and low power loss. Reconfigurable cavity filters using metal plungers have been reported in recent literatures [13]-[17], which can adjust the resonators' size and consequently adjust the center frequency. To reduce the power loss caused by the poor mechanical and electrical contacts, a contactless tunable cavity filter is reported in [18]. Another reconfiguration technique is used metal screws/posts to adjust the loaded capacitance of the cavity resonator and then to tune the center frequency [19], [20]. Microfluidically reconfigurable cavity filters based on liquid-actuated metal post [21], [22] are proposed to achieve more flexible frequency tuning than the nonfluid technique proposed in [13]-[20]. The electrically tuned filters, such as using piezoelectric actuator [23] and MEMS [24], can achieve fast tuning mechanism. However, they usually suffer from sensitive fabrication and assembly, which reduce their power handling capacity, as discussed in [21].

Most reported works focused on single-band filters, and few practical realizations of reconfigurable multiband filters have been reported. In [4] and [25], varactor-tuned dualband

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In this article, a novel reconfiguration technique for cavity filter using fluid dielectric is proposed. The cavity mode is perturbed by the fluid dielectric, which can produce a varying effective permittivity and realize the frequency tuning. The distilled water is chosen as the loaded dielectric for its high permittivity and low cost. Besides, the fluid property of the distilled water can achieve easier, faster, and more flexible tuning mechanism than the solid dielectric post, as the distilled water can be easily controlled by injecting or removing the water in the tubes using the electrical-controlled micropump. The triple-mode resonator (TMR) with resonant modes TE_{101} , TE_{011} , and TM_{110} is then used to realize tri-band reconfiguration. The resonant modes are only affected by the water post (WP) parallel to their own electric fields. Thus, each mode can be individually tuned by adjusting their corresponding WPs without the effect on other resonant modes. The proposed approach shows high feasibility in the design of reconfigurable cavity filters. A single-band and tri-band filters based on single-mode and triple-mode cavity resonators are presented. The measurement of a second-order tri-band filter verifies the design concept. Furthermore, a fully reconfigurable tri-band filter is presented. Additional WPs are employed to control the external couplings and interresonator couplings of the three passbands, which can enhance the tuning range and can also achieve constant bandwidths during the frequency tuning.

II. FLUID-DIELECTRIC RECONFIGURATION TECHNIQUE FOR CAVITY RESONATOR

A. Basic Principal of Cavity Resonator Using Fluid Dielectric

The configuration of the proposed frequency-tuning cavity resonator is plotted in Fig. 1(a) with marked dimensions. The horizontal slot is used to excite the TE_{101} mode, whose long side is perpendicular to the electric field of the TE_{101} mode (E_y), and the resonant frequency is calculated as follow:

$$f(\mathrm{TE}_{101}) = \frac{v}{2\sqrt{\varepsilon_{\mathrm{eff}}}} \sqrt{\left(\frac{1}{a}\right)^2 + \left(\frac{1}{c}\right)^2} \tag{1}$$

where v is the light speed in the air, ε_{eff} is the effective permittivity corresponding to the TE₁₀₁ mode, a and c are the side lengths of the metal cavity. According to the abovementioned equation,

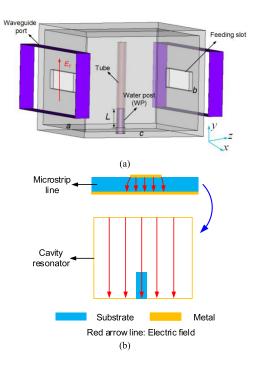


Fig. 1. (a) Three-dimensional view of proposed frequency-tuning cavity resonator with a = 45 mm, b = 50 mm, c = 50 mm. (b) Planar and cavity structures with loaded substrate.

the tunable frequency can be achieved in the following two main approaches:

- adjust *a* or *c*, i.e., the size of the resonator, which can be referred to [13]–[17];
- 2) adjust effective dielectric permittivity ε_{eff} .

The planar structures, such as a MS line, the dielectric substrate below the MS line affects the electric field, and then introduce the frequency shift, this inspires us to place a substrate inside the cavity with the direction along the electric field of the resonant mode, as show in Fig. 1(b), which can also introduce the frequency shift. Thus, a tube along y-direction filled with distilled water is put at the center of XZ-plane, as shown in Fig. 1(a). All the waveguide ports used in this article are WR284 standard waveguides.

$$\Delta f_{L,L+d} = f_L - f_{L+d} = \left(\frac{\sqrt{\varepsilon_{\text{eff}}^{L+d}} - \sqrt{\varepsilon_{\text{eff}}^{L}}}{\sqrt{\varepsilon_{\text{eff}}^{L+d}} \cdot \sqrt{\varepsilon_{\text{eff}}^{L}}}\right)$$
$$\cdot \frac{v}{2}\sqrt{\left(\frac{1}{a}\right)^2 + \left(\frac{1}{c}\right)^2}$$
$$= \left(\frac{\Delta \varepsilon_{\text{eff}}^{L+d}}{(\varepsilon_{\text{eff}}^{L} + \Delta \varepsilon_{\text{eff}}^{L+d})\sqrt{\varepsilon_{\text{eff}}^{L}} + \varepsilon_{\text{eff}}^{L}\sqrt{\varepsilon_{\text{eff}}^{L} + \Delta \varepsilon_{\text{eff}}^{L+d}}}\right)$$
$$\cdot \frac{v}{2}\sqrt{\left(\frac{1}{a}\right)^2 + \left(\frac{1}{c}\right)^2}$$
(2)

$$\Delta \varepsilon_{\text{eff}}^{L,L+d} = F(L,d,\varepsilon_r,r).$$
(3)

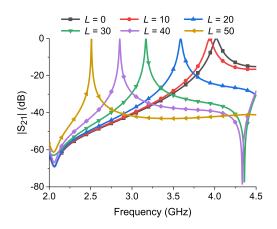


Fig. 2. Simulated $|S_{21}|$ with different length of loaded WP.

Equation (2) gives the frequency variation produced by the varied length of WP, where $\Delta f_{L,L+d}$ and $\Delta \varepsilon_{\text{eff}}^{L,L+d}$, respectively, represent the variations of frequency and effective permittivity when the post length is increased from L to L+d, while f_L , f_{L+d} , $\varepsilon_{\text{eff}}^{L}$, and $\varepsilon_{\text{eff}}^{L+d}$ represent the resonant frequencies and effective permittivity corresponding to the post length L and L+d, respectively. d is the increment of post length. The varied effective permittivity is depended on different perturbations on the cavity mode TE₁₀₁. The perturbation is produced by the loaded water. Thus, the $\Delta \varepsilon_{\text{eff}}^{L,L+d}$ is a function of L, d, ε_{r} , and r, as given in (3), which is the intrinsic factor that produces the frequency tuning. According to (2), a large $\Delta \varepsilon_{\text{eff}}^{L,L+d}$ can produce a large $\Delta f_{L,L+d}$. As the electric field is not uniformly distributed in the cavity, especially under the perturbation of the WP, same increment of WP in different starting length will cause different perturbation on the cavity mode, and then produce different $\Delta \varepsilon_{\text{eff}}^{L,L+d}$ as well as the $\Delta f_{L,L+d}$, which can be expressed as the following equations. Besides, it is easy to obtain that for a same starting post length L, a larger increment d can produce a larger frequency shift.

$$\Delta \varepsilon_{\text{eff}}^{L,L+d} \neq \Delta \varepsilon_{\text{eff}}^{L+s,L+s+d} \tag{4}$$

$$\Delta f_{L+d,L} \neq \Delta f_{L+s+d,L+s}.$$
(5)

B. Frequency Tuning

The frequency tuning produced by the varied WP is then presented. Fig. 2 shows the simulated $|S_{21}|$ with respect to the length of WP, which can give a direct insight into the frequency tuning of the proposed design concept. We see that the resonant frequency of the filter shifts to the lower frequency when increasing the length of WP, which is due to that longer WP produces increasing perturbation on the mode, and enlarges the varied effective permittivity $\Delta \varepsilon_{\text{eff}}^{L,L+d}$ and then produces a larger frequency shift. Besides, it can be also seen that the same increment of post length d = 10 mm at different initial length of the WP produce different frequency shifts, e.g., $\Delta f_{0,10}$ is about 80 MHz, while $\Delta f_{20,30}$ is about 420 MHz, as analyzed in (4) and (5). This indicates that the frequency shift produced by the

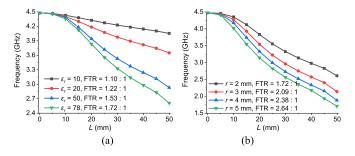


Fig. 3. Comparison of tuning range versus. (a) Different permittivity ε_r . (b) Different radius *r*.

loaded dielectric post is not a simple function of the dielectric volume.

In a substrate-based planar structure, higher permittivity can obtain lower frequency for the same size of the resonator. Similarly, substrate with lower/higher permittivity applied to Fig. 1(a) will introduce a smaller/larger frequency tuning range. Fig. 3(a) plots the tuning range with different permittivity $\varepsilon_{\rm r} =$ 10/20/50/78. The resonant frequencies here are obtained using the eigenmode solver of CST simulator, which can present an accurate effect of the dielectric post on the resonant frequencies without other loading effects, such as feeding slots (FSs). The frequency tuning ratios (FTRs) with four permittivity are 1.10, 1.22, 1.52, and 1.72, respectively. The FTR is defined as FTR = $f_{\rm max}/f_{\rm min}$, where $f_{\rm max}$ is the highest center frequency, and $f_{\rm min}$ is the lowest center frequency within the tuning range. Thus, a higher permittivity can be used to obtain a larger tuning range. The distilled water has high permittivity but low cost and easy access.

Then, the radius of the WP is considered, as shown in Fig. 3(b). It can be seen that the tuning range can be widen by introducing a large post radius. The FTR is increased from 1.72:1 to 2.64:1 when the radius is increased from 2 to 5 mm.

In practical realization of a proposed reconfigurable cavity filter, the length L is used to tune the resonant frequency, as the amount of distilled water can be easily controlled by injecting or removing the water in the tubes using the electrical-controlled micropump, which is superior to a solid dielectric post.

C. Unloaded Q-Factor

The unloaded Q-factor Q_u of a cavity-based resonator is determined by three parts: conductor loss, dielectric loss, and radiation loss. Thus, the Q_u is calculated using the following equation:

$$\frac{1}{Q_{\rm u}} = \frac{1}{Q_{\rm uc}} + \frac{1}{Q_{\rm ud}} + \frac{1}{Q_{\rm ur}} \tag{6}$$

where Q_{uc} is Q_u only with conductor loss, Q_{ud} is Q_u only with dielectric loss, Q_{ur} is Q_u only with radiation loss. As proposed cavity resonator is a closed structure, the radiation loss is neglected. The metal used for the cavity is lossy copper with electrical conductivity of 5.8e+7 S/m.

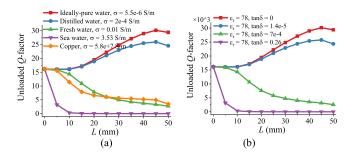


Fig. 4. Unloaded *Q*-factor. (a) Against different types of water and copper metal post. (b) Against dielectric materials with different loss tangent.

Fig. 4(a) shows the $Q_{\rm u}$ of the cavity resonator affected by different types of the water and copper metal post. The water model in the simulator (CST and HFSS) is defined as the dielectric with $tan \delta = 0$, but with a nonzero electrical conductivity, as given in Fig. 4(a). The increasing length of metal post results in decreasing $Q_{\rm u}$ due to the increasing conductor loss. Different types of water have different effect on $Q_{\rm u}$. The increasing amount of water can enhance the binding effect on the electromagnetic (EM) field and reduce the EM energy dissipating on the conductor walls. However, the nonzero electrical conductivity will produce extra power loss. The ideally pure and distilled water (used in this work) have very small electrical conductivity. Thus, the power loss can be neglected, which consequently improves the $Q_{\rm u}$ when L increases. As a result, they both have higher $Q_{\rm u}$ than the copper metal post. The fresh water and sea water have, respectively, electrical conductivity of 0.01 and 3.53 S/m. The power loss of water dominates the $Q_{\rm u}$, and the increasing amount of L causes a decreasing $Q_{\rm u}$. Thus, the power loss produced by the nonzero electrical conductivity of water can be equivalent to a dielectric with nonzero loss tangent and zero electrical conductivity. Fig. 4(b) shows the $Q_{\rm u}$ affected by four dielectrics with purposely given loss tangents. It can be seen that each dielectric has same effect on $Q_{\rm u}$ compared to each type of water, e.g., the distilled water can be as a dielectric with loss tangent 1.4e-5, and the fresh water can be as a dielectric with loss tangent 0.0007. While the seawater has large electrical conductivity and acts as a dielectric with loss tangent up to 0.26, these corresponding relationships are obtained under the particular dimensions of the proposed resonator.

D. Tri-Band Reconfiguration Based on TMR

To achieve a tri-band filter, a triple mode cavity resonator is introduced. The most-used rectangular waveguide (RWG) mode is the TE₁₀₁, which has a pure y-direction electric field, as shown in Fig. 5(a). In fact, there are two other RWG modes with the pure x-direction and pure z-direction electric field, which are corresponding to TE₀₁₁ and TM₁₁₀ modes, as shown in Fig. 5(b) and (c), respectively. These three modes are isolated to each other due to the orthogonal field distributions. Their resonant frequencies are calculated using the following equations, where

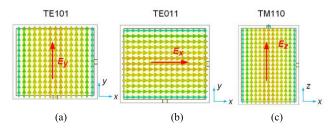


Fig. 5. Electric field distribution of three RWG orthogonal modes. (a) TE_{101} (E_y). (b) TE_{011} (E_x). (c) TM_{110} (E_z).

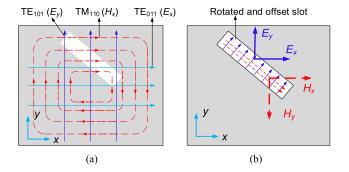


Fig. 6. (a) Electric field distributions of TE_{101} , TE_{011} and magnetic field distribution of TM_{110} . (b) Excitation mechanism. Solid-arrow line: Electric field; Dash-arrow line: Magnetic field.

each mode is determined by two side's lengths of the cavity:

$$f_1(\text{TE}_{101}) = \frac{v}{2\sqrt{\varepsilon_{\text{eff}}^I}} \sqrt{\left(\frac{1}{a}\right)^2 + \left(\frac{1}{c}\right)^2}$$
(7a)

$$f_2(\text{TE}_{011}) = \frac{v}{2\sqrt{\varepsilon_{\text{eff}}^{II}}} \sqrt{\left(\frac{1}{b}\right)^2 + \left(\frac{1}{c}\right)^2}$$
(7b)

$$f_3(\mathrm{TM}_{110}) = \frac{v}{2\sqrt{\varepsilon_{\mathrm{eff}}^{III}}} \sqrt{\left(\frac{1}{a}\right)^2 + \left(\frac{1}{b}\right)^2} \qquad (7c)$$

where v is the light speed in the air, $\varepsilon_{\text{eff}}^{I}$, $\varepsilon_{\text{eff}}^{II}$, and $\varepsilon_{\text{eff}}^{II}$ are the effective permittivity corresponding to TE₁₀₁, TE₀₁₁, and TM₁₁₀ modes, respectively, *a*, *b*, and *c* are the side lengths of the metal cavity.

These three modes are inherent property of the RWG resonator; however, to use these modes to design practical components, the excitation method of the three modes is first discussed. Fig. 6(a) shows the electric field distribution of TE_{101} , TE_{011} and the magnetic field distribution of TM_{110} at *XY*-plane where FS locates. Clearly, the horizontal slot can excite TE_{101} and the rotated slot can excite the TE_{101} , TE_{011} mode by the electric components. These two types of slots cannot excite TM_{110} as the integral of TM_{110} 's magnetic field within the nonoffset slot is zero due to the center-symmetry structures. Thus, an offset slot is needed to excite TM_{110} . As a result, a rotated and offset slot can excite all the three modes, as shown in Fig. 6(b).

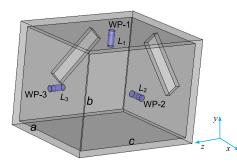


Fig. 7. Proposed tri-band frequency-tuning cavity resonator with a = 65 mm, b = 56 mm, and c = 80 mm.

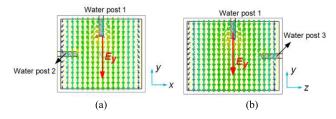


Fig. 8. Effect of the WPs on the electric field distribution of TE_{101} (E_y) mode. (a) Post 1 and post 2. (b) Post 1 and post 3.

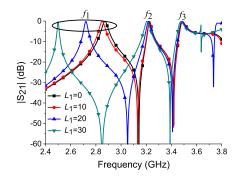


Fig. 9. Frequency-tuning of the TMR against L_1 .

The configuration of single-cavity tri-band filter is shown in Fig. 7. The rotated and offset FSs are used to excite these three modes. Three WPs at the centers of three orthogonal metal walls are used to tune the frequency. Then, we first analyzed how the WPs in different positions affect the resonant modes. For instance, the effect of the three WPs on the TE_{101} mode is shown in Fig. 8. It can be seen that only WP 1, which has same direction of TE_{101} 's electric field, perturbs the electric field and produces a varied εI eff to obtain a frequency shift of TE₁₀₁, which can be referred to (7a). Similarly, WPs 2 and 3 perturb the electric field of TE₀₁₁ and TM₁₁₀ modes and produce varied $\varepsilon_{\rm eff}^{II}$ and $\varepsilon_{\rm eff}^{III}$ to obtain frequency shifts of TE₀₁₁ and TM₁₁₀ modes, respectively. Thus, each WP only causes the frequency shift of its corresponding resonant modes whose electric-field's direction is parallel to the WP. Fig. 9 shows the frequency-tuning of the TMR versus varying WPs' lengths L_1 . The varying length of WP-1 (L_1) only cause frequency shift of f_1 without effect on f_2 and f_3 . Similarly, L_2 and L_3 only affect f_2 and f_3 , respectively.

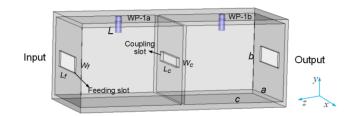


Fig. 10. Configuration of second-order single-band filter using two cavities with same size.

This is an attractive property that all the three resonant modes can be individually tuned by their corresponding WPs without the effect on other resonant modes.

III. DESIGN OF RECONFIGURABLE FILTERS

A. Single-Band Reconfigurable Filter

Then, the proposed reconfiguration technique is used to design reconfigurable bandpass cavity filters. Fig. 10 shows the configuration of a second-order single-band filter using two identical metal cavities. Each cavity produces a TE_{101} mode and couples to each other through the coupling slots (CSs) between the two cavities, and two WPs are placed at the center of the top walls of each cavity.

First, the filter synthesis method is utilized to design the second-order bandpass filter, the external Q-factor and coupling coefficients can be calculated as [30]

$$Q_e = \frac{g_0 g_1}{\text{FBW}}, \ K_{12} = \frac{\text{FBW}}{\sqrt{g_1 g_2}}$$
 (8)

where g_0 , g_1 , and g_2 are the low-pass prototype element values of the second-order Butterworth polynomial, which can be set as $g_0 = 1$, $g_1 = g_2 = 1.4142$. With the specifications of 3% fractional bandwidth (FBW), $Q_e = 47$ and $K_{12} = 0.021$ are obtained.

For the practical filter, the Q_e and K are extracted using the following formulas [30]:

$$Q_e = \frac{f_0}{\Delta f_{3-\mathrm{dB}}}, K = \pm \frac{f_{p1}^2 - f_{p2}^2}{f_{p1}^2 + f_{p2}^2}$$
(9)

where f_{p1} and f_{p2} are the resonant frequencies of the two coupled resonators, f_0 is the center frequency, $\operatorname{and}\Delta f_{3-dB}$ is bandwidths between $+/-90^\circ$ phase offsetting of the resonant frequency, respectively. For this cavity filter, the Q_e and K_{12} can be controlled by modifying the sizes of FSs and CS, respectively. The optimized result of the bandpass filter is shown in Fig. 11 with L = 0, the filter operates at 3.38 GHz with 104 MHz 3-dB bandwidth (BW). The physical dimensions of the proposed single-band filter are given in Table I, the radius of WPs is fixed at 2 mm.

As analyzed in Section II, the frequency tuning is achieved by modifying the amount of water in the tube. Fig. 11 shows the simulated *S*-parameter with varying WPs' lengths, the tuning range is from 3.95 to 2.73 GHz (1.22 GHz) with the return loss better than 10 dB, and the FTR is 1.45:1, while the insertion loss

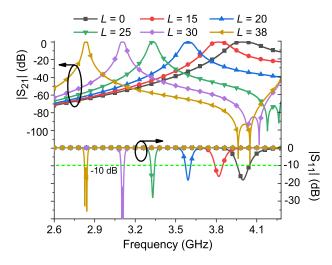


Fig. 11. Simulated results of the second-order single-band filter with varying WPs' lengths.

TABLE I PHYSICAL DIMENSIONS OF SINGLE-BAND FILTER

Symbol	а	b	С	L_{f}	W_{f}	L_c	W_c
Value (mm)	50	50	50	27.5	28	28.5	4

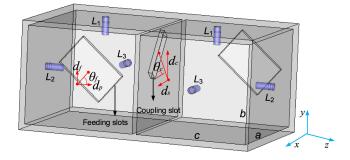


Fig. 12. Configuration of the reconfigurable second-order tri-band filter with two cavity. (Solid dots: Center points of the slots or walls).

has small deterioration from 0.1 to 0.5 dB. The narrowed BW, as plotted in Fig. 11, is due to that the increasing amount of the water enhance the concentration of the EM field around the water and reduces the coupling energy between the two-coupled cavity resonators.

B. Tri-Band Reconfigurable Filter

The last section shows the application of a proposed reconfiguration technique in filter design. Based on that, a tri-band reconfigurable filter is presented. Here, a second-order tri-band reconfigurable filter using two identical cavities is designed, and the configuration is shown in Fig. 12. As analyzed in the last section, the rotated and offset slots can excite the three modes, in the design of the tri-band filter, the feeding and CSs are all rotated and offset. The FSs (length L_f , width W_f) are placed with the rotation angle θ_f , offsetting d_f in y-direction and offsetting d_p in z-direction, and the CS (length L_c , width W_c)

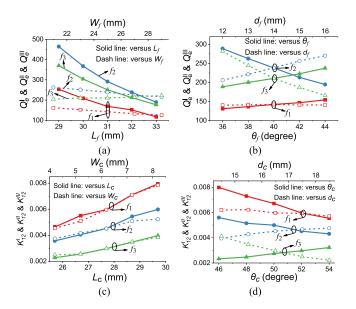


Fig. 13. Variation trend versus physical parameters. (a) and (b) External *Q*-factors Q_e^{\dagger} , Q_e^{\parallel} , and $Q_e^{\parallel \parallel}$. (c) and (d) Coupling coefficients K_{12}^{\dagger} , K_{12}^{\parallel} , and $K_{12}^{\parallel \parallel}$.

TABLE II PHYSICAL DIMENSIONS OF TRI-BAND FILTER

а	b	С	L_f	W_{f}	L_c	W_c
75 mm	55 mm	63 mm	31.1 mm	27.3 mm	27.7 mm	6.4 mm
d_{f}	d_p	d_c	d_s	θ_{f}	θ_c	
7.6 mm	6.6 mm	14.3 mm	4.2 mm	40.5°	52°	

is placed with rotation angle θ_c , offsetting d_c in y-direction and offsetting d_s in x-direction. Each cavity has three orthogonal WPs corresponding to the three modes, respectively. The WPs' lengths corresponding to $f_1(E_y), f_2(E_x), \text{ and } f_3(E_z)$ are L_1, L_2 , and L_3 , respectively.

Herein, the second-order tri-band filters are synthesized using Butterworth polynomial [30]. With the specifications of 0.9%, 0.7%, and 0.5% for the first, second, and third bands, respectively, the external *Q*-factors and coupling coefficients are calculated as

$$Q_e^I = 157, Q_e^{II} = 202, Q_e^{III} = 282$$

 $K_{12}^I = 0.0064, K_{12}^{II} = 0.0049, K_{12}^{III} = 0.0035.$

The extracted external *Q*-factors and coupling coefficients versus the physical dimensions are plotted in Fig. 13 using the formula (9). Then, by properly setting the suitable values specified in Fig. 13 to meet the calculated external *Q*-factors and coupling coefficients, the desired filtering responses are obtained. As shown in Fig. 14(a)–(c) with the condition of L = 0, the first band operates at 3.03 GHz with BW 27.2 MHz, the second band operates at 3.62 GHz with BW 17.1 MHz, and better than 20 dB RLs are achieved. The physical dimensions are given in Table II, the radius of WPs are fixed at 2 mm.

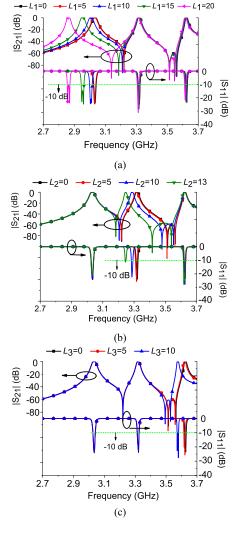


Fig. 14. Simulated results of the second-order tri-band filter versus different posts' length. (a) L_1 . (b) L_2 . and (c) L_3 .

Fig. 14 also shows the simulated results of the tri-band filter with different length of WPs. Fig. 14(a) indicates that the variation of L_1 only causes the frequency shift of band 1, while it has little effect on band 2 and band 3, which is a distinguished feature of this design. Fig. 14(b) and (c) is similar to the analysis of Fig. 14(a). ILs increase slightly from 0.1 to 0.5 dB, and the FBWs become narrow due to the increasing binding effect of WP. The tuning percentages and tuning ranges of the three bands are 5.9% (169 MHz), 2.5% (80 MHz), and 1.7% (60 MHz) with return loss better than 10 dB, respectively, where the tuning percentage is defined as

$$\eta = \frac{f_{\max} - f_{\min}}{f_{\min}} \times 100\%. \tag{10}$$

IV. EXPERIMENTAL RESULTS

To validate the concept, the proposed reconfigurable tri-band filter is fabricated and measured. Fig. 15 shows the photographs of the fabricated tri-band filter and the actuation mechanism. The filter is measured and tuned by adjusting the amount of

Fig. 15. Actuation mechanism of the proposed filter.

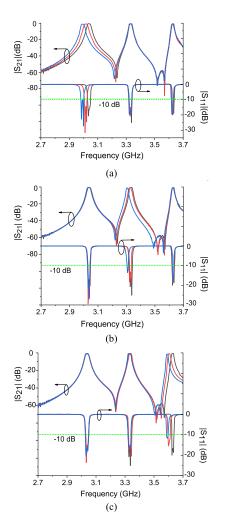


Fig. 16. Measured results. (a) Frequency tuning of band 1. (b) Frequency tuning of band 2. (c) Frequency tuning of band 3.

distilled water in the tubes; the water level inside the tube can be adjusted by injecting or removing the water via the electricalcontrolled micropump. The water can stick to the tubes by itself via the tension and atmospheric pressure due to its small density and gravity. The measured results are shown in Fig. 16(a)-(c) for bands 1–3, respectively. We see that each channel can be

	Band 1	Band 2	Band 3
$f_{\text{max}}/f_{\text{min}}$ (GHz)	3.035/2.986	3.335/3.3	3.632/3.588
TR (MHz)	50	35	44
η	2.3%	1.1%	1.2%
IL (dB)	0.7/1.1	0.75/1.1	0.75/1.15
FBW	0.95%/0.85%	0.71%/0.46%	0.5%/0.38%

TABLE III MEASURED RESULTS OF RECONFIGURABLE TRI-BAND FILTER

Note: f_{\max}/f_{\min} : highest/lowest frequency; TR: tuning range; η : tuning percentage; IL: insertion loss; FBW: fractional bandwidth.

individually tuned with little effect on other two bands. As the amount of water can be tuned continuously, the individual and continuous reconfiguration of the proposed tri-band filter can be obtained. The measured results are concluded in Table III. There are some discrepancies between the simulated and measured results due to the fabrication tolerance and roughness of metal surface. In general, the two results both show that the proposed concept has feasibility in the design of reconfigurable multiband cavity filters.

The tunable filter is measured at a static state of water, but allows a varying amount of water to achieve frequency tuning. The flowing water means a fixed amount of water and is not suitable for achieving the frequency tuning. Besides, a slow velocity and a small pressure are more suitable for injecting small and precise amount of the water to achieve the continuous and precise frequency tuning.

V. FULLY RECONFIGURABLE TRI-BAND FILTER

The simulated and measured prototype of the reconfigurable tri-band filter using the distilled water verifies the proposed design concept. As the external couplings and interresonator couplings cannot be tuned when tuning the operating frequencies, which cause the narrowed BW and narrowed tuning range. To tackle these issues and further show the feasibility of the proposed reconfiguration technique, a fully reconfigurable tri-band filter with all the controlling of operating frequencies, external couplings, and interresonator coupling is designed.

The physical structure of the filter is shown in Fig. 17. The conventional standard waveguide port is replaced by the coaxialto-waveguide transition composed of a feeding cavity, a FS and a probe, as shown in Fig. 17(a). The single CS is replaced by three CSs, i.e., CS-1, CS-2, and CS-3, as shown in Fig. 17(b). These three CSs are the independent coupling structures related to band 1, band 2, and band 3, respectively, which can be referred to Fig. 6. The CS-1 only produce the coupling of the mode with electric filed E_v , the CS-2 only produce the coupling of the mode with electric filed E_z (or magnitude field H_x), while the CS-3 only produce the coupling of the mode with electric filed E_x . Three coupling water posts (CWPs) placed together with the CSs are used to achieve the individually tuned interresonator couplings of the three bands. Two feeding water posts (FWPs) close to the probes are used to obtain tuned external couplings. Three pairs of frequency-tuning water posts (FTWPs) at the center of the cavity wall are used to achieve the frequency tuning.

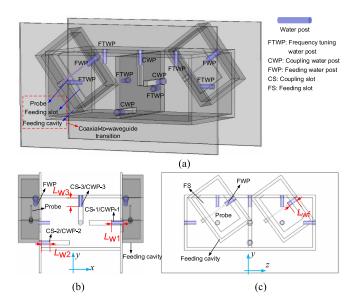


Fig. 17. Physical structure of the fully reconfigurable tri-band filter. (a) Perspective view. (b) Side view in *XY*-plane. (c) Side view in *YZ*-plane.

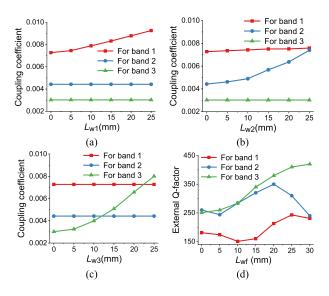
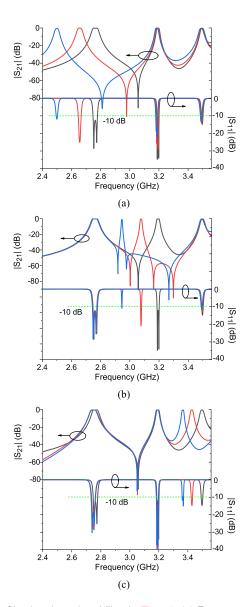


Fig. 18. Effect of the lengths on the CWPs and FWPs. (a) Coupling coefficients versus length of CWP-1. (b) Coupling coefficients versus length of CWP-2. (c) Coupling coefficients versus length of CWP-3. (d) External *Q*-factors versus length of FWP.

Fig. 18 shows the effect of the lengths of the CWPs and FWPs on the coupling coefficients and external *Q*-factors. It can be seen that the enlarged CWPs corresponding to each band can enhance the interresonator coupling, as the CWP can concentrate the EM field around the CS and enhance the coupling energy between the resonators. Besides, each CWP only has effect on its related band. These results also indicate that the coupling of each band can be individually controlled by its related CS and CWP. While the enlarged FWPs will simultaneously affect the external couplings of the three bands, but different effects on



|S₂₁| (dB) -60 -80 10 dB |S₁₁| (dB) 20 30 40 2.6 3.0 2.4 2.8 3.2 3.4 Frequency (GHz) (a) 0 -20 S₂₁ (dB) -40 -60 -80 10 -10 dB |S₁₁| (dB) -20 30 40 24 2.6 28 3.0 32 34 Frequency (GHz) (b) 0 -20 |S₂₁| (dB) -6(-80 -10 dB -10 |S₁₁| (dB) -30 -40 2.6 3.0 2.4 2.8 3.2 3.4 Frequency (GHz) (c)

Fig. 19. Simulated results of filter in Fig. 17. (a) Frequency tuning of band 1. (b) Frequency tuning of band 2. (c) Frequency tuning of band 3.

Fig. 20. Simulated results with constant bandwidth. (a) Frequency tuning of band 1. (b) Frequency tuning of band 2. (c) Frequency tuning of band 3.

the three bands, which can still help to tune the in-band filtering performance when tuning the frequency and bandwidth. The enlarged FTWP cause a decreasing resonant frequency, and will also narrow the bandwidths, as analyzed previously.

Then, an enhanced-tuning-range tri-band filter is designed and optimized. The simulated results are shown in Fig. 19. It can be seen that each band can be individually tuned with little effect on other two bands. Compared to the tri-band filter in Fig. 12, the tuning ranges of the three bands are increased to 10.7%, 8.6%, and 4.0%, respectively.

Furthermore, as the interresonator couplings can be individually tuned, constant bandwidths of the three bands can be realized when tuning the frequencies. The narrowed BW caused by the enlarged FTWPs when tuning the frequency can be complemented by enlarging the CWPs. The simulated results for constant bandwidths are shown in Fig. 20.

The bandwidths of the three bands can be kept constant by properly modifying the CWPs and FWPs. The simulated results shown in Figs. 19 and 20 are obtained based on the same filter with same original dimensions except the dimensions of WPs. The comparison of tunable tri-band filters shown in Figs. 12 and 17 is provided in Table IV. The filter shown in Fig. 17 has a wider tuning range and can achieve a constant BW during the frequency tuning.

The comparison with other tunable filters is provided in Table V. The proposed design concept shows the merits of high unloaded Q-factor, multiband application, multiband filter in a single multimode resonator, individual and continuous tuning, tunable BW, and electrical control.

TABLE IV COMPARISON OF THE TUNING RANGES OF TWO TRI-BAND FILTERS

Works	Tuning	Tuning range/tuning percentage					
	conditions	Band 1	Band 2	Band 3			
Fig.12	Measured Varied FBW	50MHz/2.3%	35MHz/1.1%	44MHz/1.2%			
	Simulated Varied FBW	169MHz/5.9%	80MHz/2.5%	60MHz/1.7%			
Fig.17	Simulated Varied FBW	267MHz/10.7%	252MHz/8.6%	135MHz/4.0%			
	Simulated Constant FBW	128MHz/4.9%	102MHz/3.3%	93MHz/2.7%			

TABLE V COMPARISONS WITH REPORTED TUNABLE FILTERS

Ref.	Band No.	Structu re	Reso. No.	Tune Type	Tune Tech.	Elec. Tune	Indi. Tune	Cons. BW	$Q_{\rm u}$
[4]	2	MS	2	Disc.	Varactor	Yes	Yes	No	Low
[11]	1	CPW	1	Disc.	Liquid Metal	No.	N.A.	No	Low
[20]	3	Coaxial cavity	3	Cont.	Metal Screw	No	Yes	No	High
[21]	1	Coaxial cavity	1	Cont.	Liquid Metal	Yes	N.A.	Yes	Middle
[23]	1	Coaxial cavity	1	Cont.	Piezo actuator	Yes	N.A.	Yes	Middle
[29]	4	MS	4	Cont.	Varactor	Yes	Yes	Yes	Low
T.W. Fig.12	3	RWG	1	Cont.	Fluid Dielectric	Yes	Yes	No	High
T.W. Fig.17	3	RWG	1	Cont.	Fluid Dielectric	Yes	Yes	Yes	High

Band No.: Number of passbands; Reso. No.: Number of resonators for the multiband; Filter structure; Tune Tech.: Tune technique; Elec. Tune: Electrical tune; Indi. Tune: Individual tune; Cons. BW: Constant bandwidth; Q_u ; Unloaded *Q*-factor; MS: MS line; CPW; Coplanar waveguide; RWG: Rectangular waveguide; Disc.: Discrete; Cont.: Continuous; N.A.: Not applicable; T.W.: This work.

VI. CONCLUSION

In this article, a novel reconfiguration technique for cavity components based on fluid dielectric was proposed. The loaded fluid dielectric, i.e., distilled water, produced an effective permittivity corresponding to the cavity mode, and then realized the frequency tuning. Then, a TMR with orthogonal electric field distributions was investigated to achieve the tri-band reconfigurable filter with individual frequency tuning. The distilled water allowed an easy, fast, and flexible tuning mechanism by controlling the micropump to inject or remove accurate amount of water in the tubes. High permittivity and low dielectric loss brought in large tuning range and low insertion loss. Reconfigurable single-band and tri-band filters were then designed, and the measurement of the tri-band filter verified the design concept. A fully reconfigurable tri-band filter was finally presented to show that the fluid dielectric had high feasibility and attractive feature in designing reconfigurable cavity filters.

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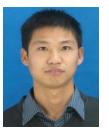


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